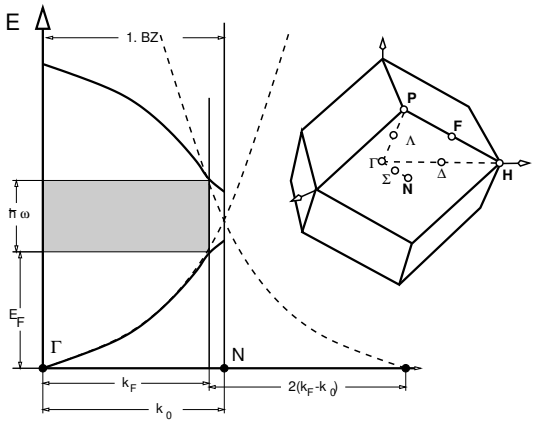
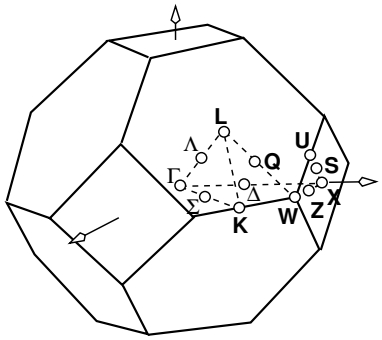
5. Bandstruktur und Eigenschaft

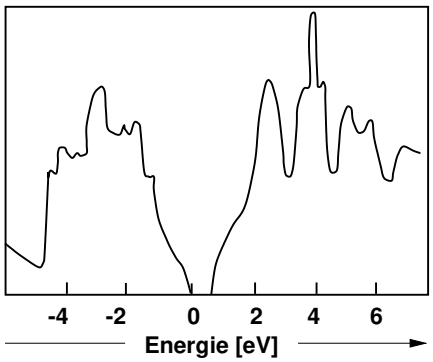
5.1/5.2. Metallische Leiter/Halbleiter



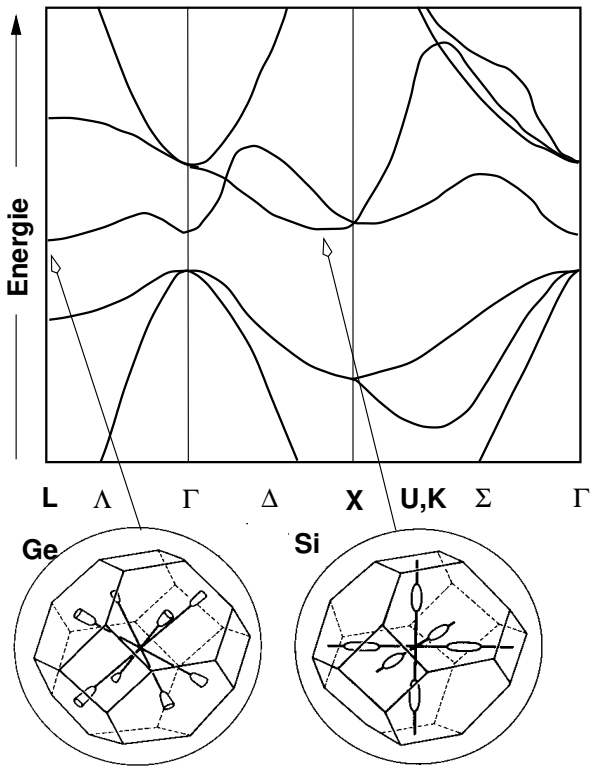
Alkalimetalle: Interbandabsorption



fcc: Brillouin-Zone



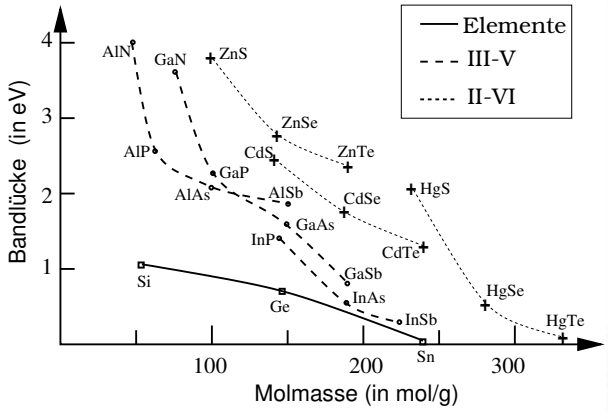
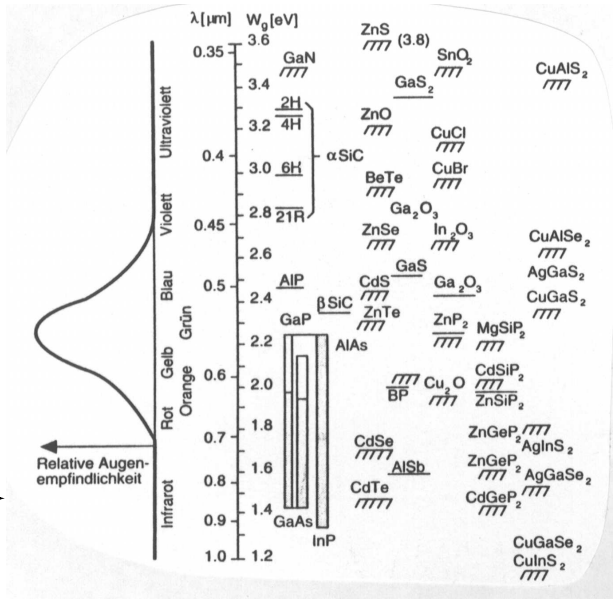
Zustandsdichte von Si



Halbleiter: charakteristische Bandstruktur

Substanz	Bandlücke	E_g [eV] bei 0 K
C (Diamant)	i	5.4
Si	i	1.17
Ge	i	0.744
Sn (α)	d	0
As		klein
Sb	d	0
Bi	d	0
Se		2.2
Te	d	0.33

Bandlücken



Bandlücke bei Verbindungshalbleitern